

Features

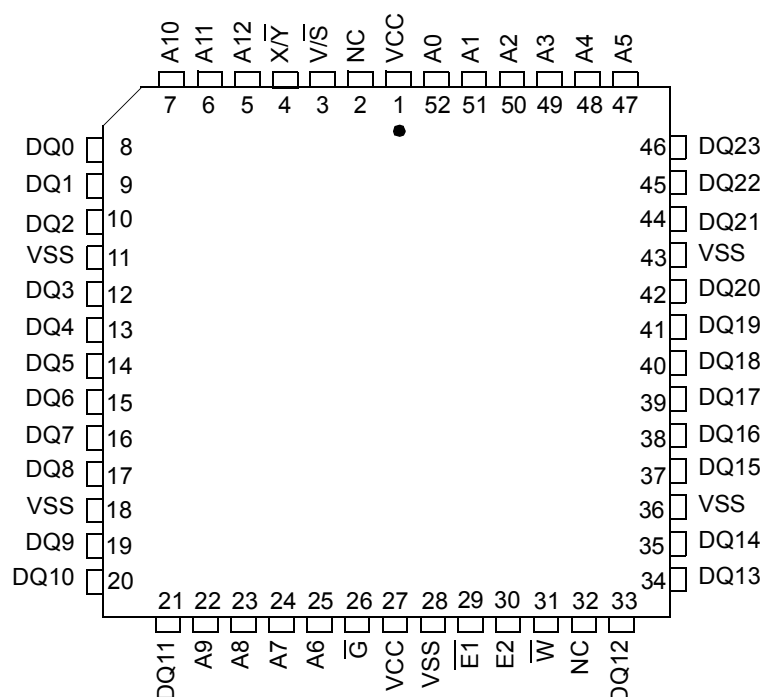
- ❑ 196 608 bit static CMOS RAM
- ❑ 35 ns Access Time
- ❑ Fully static Read and Write operations
- ❑ Equal address and chip enable access times
- ❑ Single bit on-chip address multiplexer
- ❑ Active high and active low chip enable inputs
- ❑ Output enable controlled three-state outputs
- ❑ TTL/CMOS-compatible
- ❑ Low power standby mode
- ❑ Power supply voltage 5 V
- ❑ Operating temperature range
 - 0 to 70 °C
 - 40 to 85 °C
 - 40 to 125 °C
- ❑ QS 9000 Quality Standard
- ❑ ESD protection > 2000 V (MIL STD 883C M3015.7)
- ❑ Latch-up immunity > 100 mA
- ❑ Package: PLCC52

Description

The U62H824 is a static RAM manufactured using a CMOS process technology. The device integrates an 8K x 24 SRAM core with multiple chip enable inputs, output enable, and an externally controlled single address pin multiplexer. These functions allow for direct connection to the Motorola DSP56k Digital Signal Processor Family and provide a very efficient means for implementation of a reduced parts count system requiring no additional interface logic. The availability of multiple chip enable ($\overline{E}1$ and $\overline{E}2$) and output enable (\overline{G}) inputs provides for greater system flexibility when multiple devices are used. With either chip enable unasserted, the device will enter standby mode, useful in low-power applications. A single on-chip multiplexer selects A12 or $\overline{X}/\overline{Y}$ as the highest order address input depending upon the state of the $\overline{V}/\overline{S}$ control input. This feature

allows one physical static RAM component to efficiently store program and vector or scalar operands by dynamically re-partitioning the RAM array. Typical applications will logically map vector operands into upper memory with scalar operands being stored in lower memory. An application example is at the end of this document for additional information. Multiple power and ground pins have been utilized to minimize effects induced by output noise.

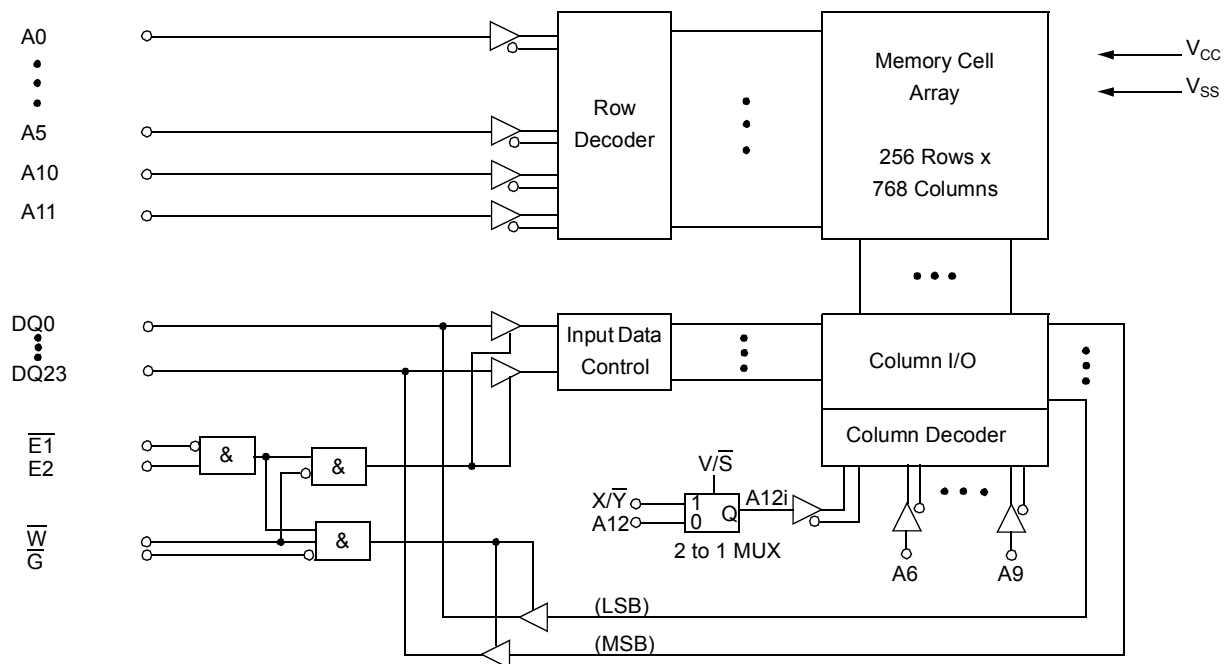
Pin Configuration



Pin Description

Signal Name	Signal Description
A0 - A11	Address Inputs
A12, $\overline{X}/\overline{Y}$	Multiplexed Address
$\overline{V}/\overline{S}$	Address Multiplexer Control
DQ0 - DQ23	Data Input / Output
$\overline{E}1, \overline{E}2$	Chip Enable
\overline{G}	Output Enable
\overline{W}	Write Enable
VCC	Power Supply Voltage
VSS	Ground
NC	Not Connected

For proper operation of the device, all V_{SS} pins must be connected to ground.



Mode	$\overline{\text{E1}}$	E2	$\overline{\text{G}}$	$\overline{\text{W}}$	V/ $\overline{\text{S}}$	Supply Current	I/O Status
Not Selected	H	*	*	*	*	I _{CC(SB)}	High - Z
Not Selected	*	L	*	*	*	I _{CC(SB)}	High - Z
Output Disable	L	H	H	H	*	I _{CC(OP)}	High - Z
Read Using X/ $\overline{\text{Y}}$	L	H	L	H	H	I _{CC(OP)}	Data Out
Read Using A12	L	H	L	H	L	I _{CC(OP)}	Data Out
Write Using X/ $\overline{\text{Y}}$	L	H	*	L	H	I _{CC(OP)}	Data In
Write Using A12	L	H	*	L	L	I _{CC(OP)}	Data In

* H or L

Characteristics

All voltages are referenced to $V_{SS} = 0$ V (ground).

All characteristics are valid in the power supply voltage range and in the operating temperature range specified.

Dynamic measurements are based on a rise and fall time of ≤ 5 ns, measured between 10 % and 90 % of V_I , as well as input levels of $V_{IL} = 0$ V and $V_{IH} = 3$ V. The timing reference level of all input and output signals is 1.5 V, with the exception of the t_{dis} -times and t_{en} -times, in which cases transition is measured ± 200 mV from steady-state voltage.

Absolute Maximum Ratings ^a	Symbol	Min.	Max.	Unit
Power Supply Voltage	V_{CC}	-0.5	7	V
Input Voltage	V_I	-0.5	$V_{CC} + 0.5$ ^b	V
Output Voltage	V_O	-0.5	$V_{CC} + 0.5$ ^b	V
Power Dissipation	P_D	-	1.75	W
Operating Temperature	T_a	0	70	°C
C-Type		-40	85	°C
K-Type		-40	125	°C
A-Type				
Storage Temperature	T_{stg}	-65	150	°C
Output Short-Circuit Current at $V_{CC} = 5$ V and $V_O = 0$ V ^c	$ I_{OS} $		20	mA

^a Stresses greater than those listed under „Absolute Maximum Ratings“ may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability

^b Maximum voltage is 7 V

^c Not more than 1 output should be shorted at the same time. Duration of the short circuit should not exceed 30 s.

Recommended Operating Conditions	Symbol	Conditions	Min.	Max.	Unit
Power Supply Voltage	V_{CC}		4.5	5.5	V
Input Low Voltage ^d	V_{IL}		-0.3	0.8	V
Input High Voltage	V_{IH}		2.2	$V_{CC} + 0.3$	V

^d -2 V at Pulse Width 10 ns

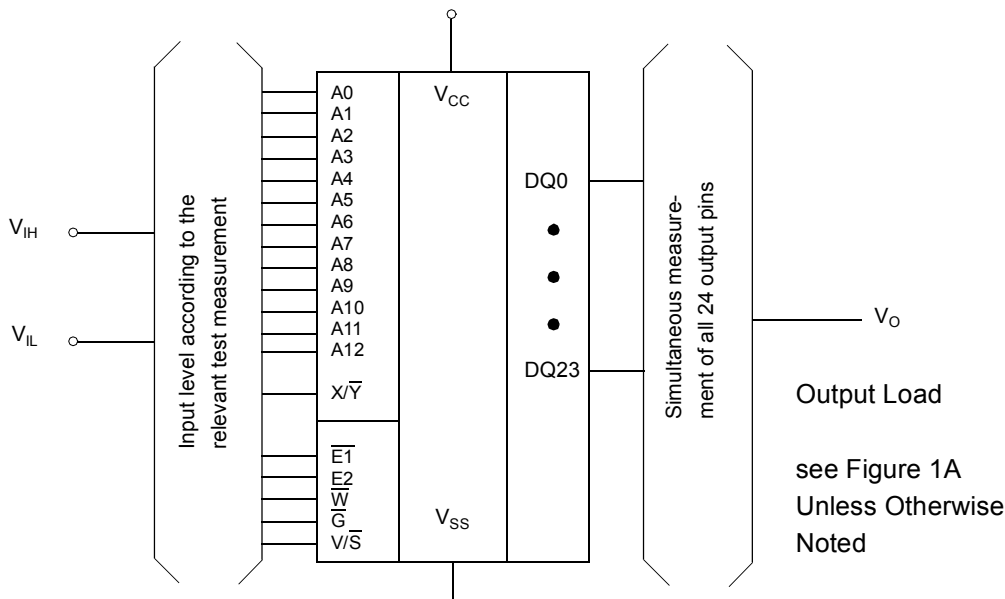
Electrical Characteristics	Symbol	Conditions	Min.	Max.	Unit
Supply Current - Operating Mode	$I_{CC(OP)}$	$V_{CC} = 5.5 \text{ V}$ $\overline{V_{E1}} = 0.8 \text{ V}$ $V_{E2} = 2.2 \text{ V}$ $\overline{V_G} = 2.2 \text{ V}$ other inputs = V_{IL} or V_{IH} $I_{out} = 0 \text{ mA}$ $t_{cW} = 35 \text{ ns}$ C/K-Type A-Type		170 180	mA mA
Supply Current - Standby Mode (CMOS level)	$I_{CC(SB)}$	$V_{CC} = 5.5 \text{ V}$ $\overline{V_{E1}} = V_{CC} - 0.2 \text{ V}$ $V_{E2} = 0.2 \text{ V}$ all inputs $\geq V_{CC} - 0.2 \text{ V}$ or $\leq 0.2 \text{ V}$ C-Type K-Type A-Type		6 8 10	mA mA mA
Supply Current - Standby Mode (TTL level)	$I_{CC(SB)1}$	$V_{CC} = 5.5 \text{ V}$ $\overline{V_{E1}} = 2.2 \text{ V}$ $V_{E2} = 0.8 \text{ V}$ all inputs = V_{IH} or V_{IL}		15	mA
Output High Voltage	V_{OH}	$V_{CC} = 4.5 \text{ V}$ $I_{OH} = -4.0 \text{ mA}$	2.4		V
Output Low Voltage	V_{OL}	$I_{OL} = 8.0 \text{ mA}$		0.4	V
Input High Leakage Current	I_{IH}	$V_{CC} = 5.5 \text{ V}$ $V_{IH} = 5.5 \text{ V}$		2	μA
Input Low Leakage Current	I_{IL}	$V_{IL} = 0 \text{ V}$	-2		μA
Output High Current	I_{OH}	$V_{CC} = 4.5 \text{ V}$ $V_{OH} = 2.4 \text{ V}$		-4	mA
Output Low Current	I_{OL}	$V_{OL} = 0.4 \text{ V}$	8		mA
Output Leakage Current High at Three-State Outputs	I_{OHZ}	$V_{CC} = 5.5 \text{ V}$ $V_{OH} = 5.5 \text{ V}$		2	μA
Low at Three-State Outputs	I_{OLZ}	$V_{OL} = 0 \text{ V}$ $\overline{V_G} = V_{IH}$	-2		μA

Switching Characteristics Read Cycle	Symbol		35		Unit
	Alt.	IEC	Min.	Max.	
Read Cycle Time	t_{RC}	t_{cR}	35		ns
Address Access Time to Data Valid	t_{AA}	$t_{a(A)}$		35	ns
MUX Control to Data Valid		$t_{a(VS)}$		35	
Chip Enable Access Time to Data Valid	t_{ACE}	$t_{a(E)}$		35	ns
\overline{G} LOW to Data Valid	t_{OE}	$t_{a(G)}$		15	ns
Output Hold Time from Address Change	t_{OH}	$t_{v(A)}$	5		ns
Output Hold Time from MUX Control Change		$t_{v(VS)}$	5		ns
$\overline{E1}$ LOW or $E2$ HIGH to Output in Low-Z	t_{LZCE}	$t_{en(E)}$	0		ns
\overline{G} LOW to Output in Low-Z	t_{LZOE}	$t_{en(G)}$	0		ns
$\overline{E1}$ HIGH or $E2$ LOW to Output in High-Z	t_{HZCE}	$t_{dis(E)}$		15	ns
\overline{G} HIGH to Output in High-Z	t_{HZOE}	$t_{dis(G)}$		15	ns

Switching Characteristics Write Cycle	Symbol		35		Unit
	Alt.	IEC	Min.	Max.	
Write Cycle Time	t_{WC}	t_{cW}	35		ns
Write Pulse Width	t_{WP}	$t_{w(W)}$	20		ns
Write Pulse Width Setup Time	t_{WP}	$t_{su(W)}$	20		ns
Address Setup Time	t_{AS}	$t_{su(A)}$	0		ns
MUX Control Setup Time		$t_{su(VS)}$	0		ns
Address Valid to End of Write	t_{AW}	$t_{su(A-WH)}$	30		ns
MUX Control Valid to End of Write		$t_{su(VS-WH)}$	30		ns
Address Valid to End of Write		$t_{su(A-E)}$	30		ns
MUX Control Valid to End of Write		$t_{su(VS-E)}$	30		ns
Chip Enable Setup Time	t_{CW}	$t_{su(E)}$	20		ns
Pulse Width Chip Enable	t_{CW}	$t_{w(E)}$	20		ns
Data Setup Time	t_{DS}	$t_{su(D)}$	15		ns
Data Hold Time	t_{DH}	$t_{h(D)}$	0		ns
Address Hold from End of Write	t_{AH}	$t_{h(A)}$	0		ns
MUX Control from End of Write		$t_{h(VS)}$	0		ns
\overline{W} HIGH to Output in Low-Z	t_{LZWE}	$t_{en(W)}$	5		ns
\overline{W} LOW to Output in High-Z	t_{HZWE}	$t_{dis(W)}$		15	ns

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Test Configuration for Functional Check



AC Test Loads

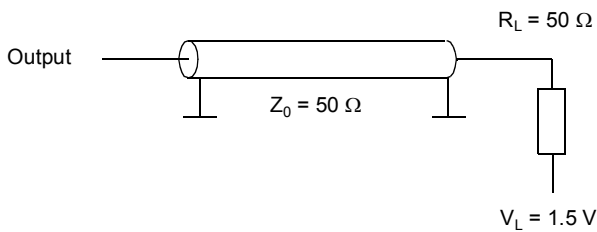


Figure 1A

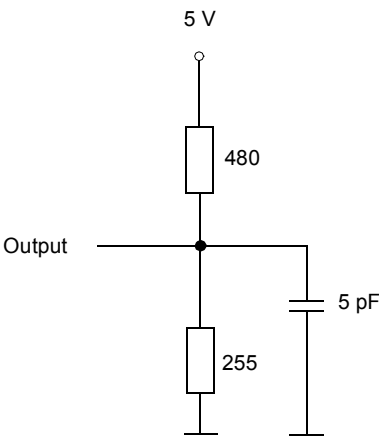


Figure 1B

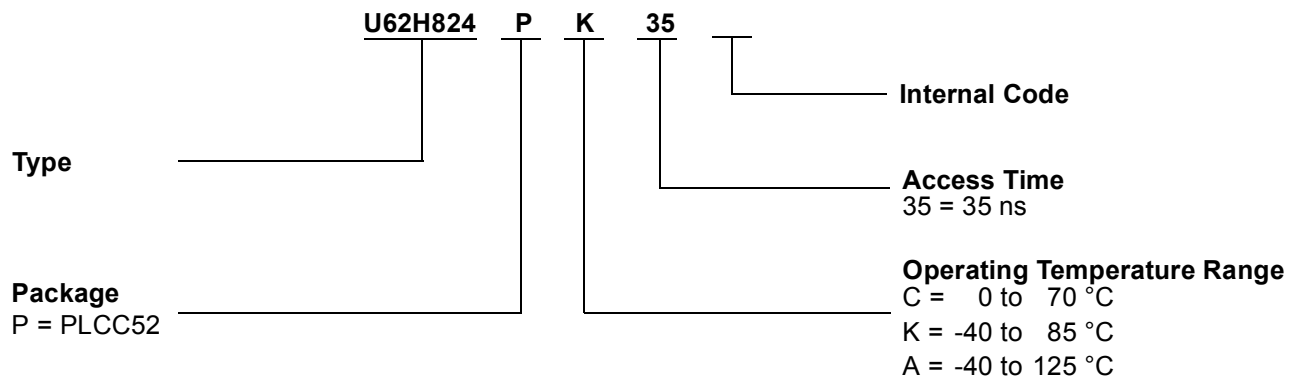
Measurement of $t_{dis(E)}$, $t_{dis(W)}$, $t_{dis(G)}$, $t_{en(E)}$, $t_{en(W)}$, $t_{en(G)}$ with Output Load from Figure 1B.

Capacitance	Conditions	Symbol	Min.	Max.	Unit
Input Capacitance	$V_{CC} = 5.0\text{ V}$ $V_I = V_{SS}$ $f = 1\text{ MHz}$	C_I		6	pF
Output Capacitance	$T_a = 25\text{ °C}$	C_O		8	pF

All pins not under test must be connected with ground by capacitors.

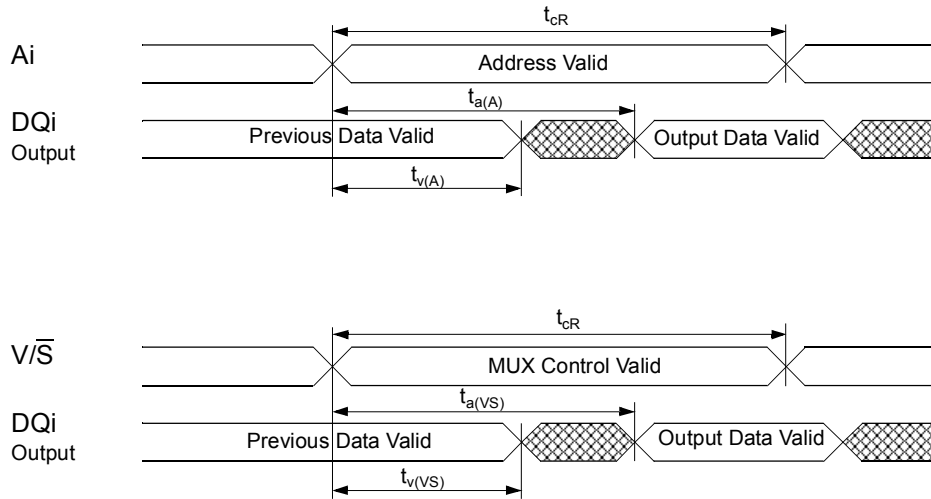
IC Code Numbers

Example



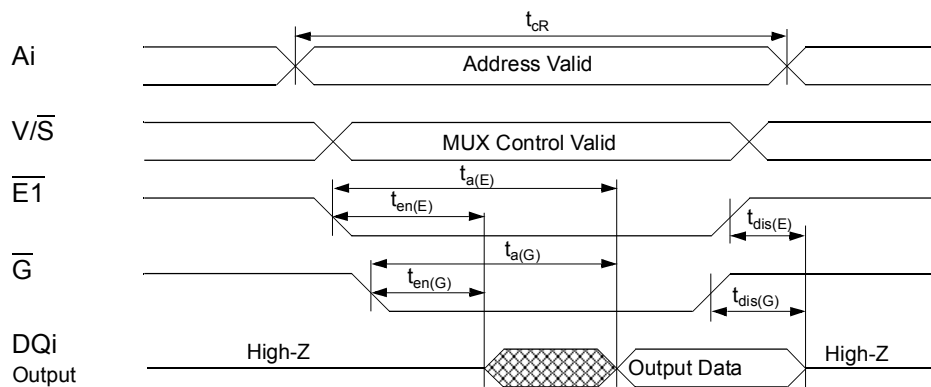
The date of manufacture is given by the last 4 digits of the mark, the first 2 digits indicating the year, and the last 2 digits the calendar week.

Read Cycle 1: Ai- or V/ \overline{S} -controlled (during Read Cycle: $\overline{E1} = \overline{G} = V_{IL}$, $E2 = \overline{W} = V_{IH}$)



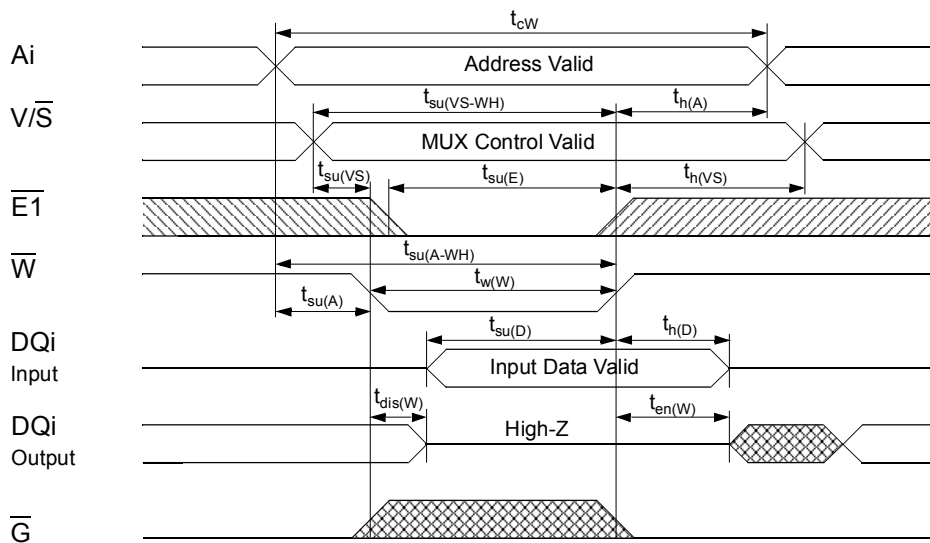
Read Cycle 2: \overline{E} -, \overline{G} -controlled (during Read Cycle: $\overline{W} = V_{IH}$)

$\overline{E1}$ in the timing diagrams represents both $\overline{E1}$ and $E2$ with $\overline{E1}$ asserted Low and $E2$ asserted High.



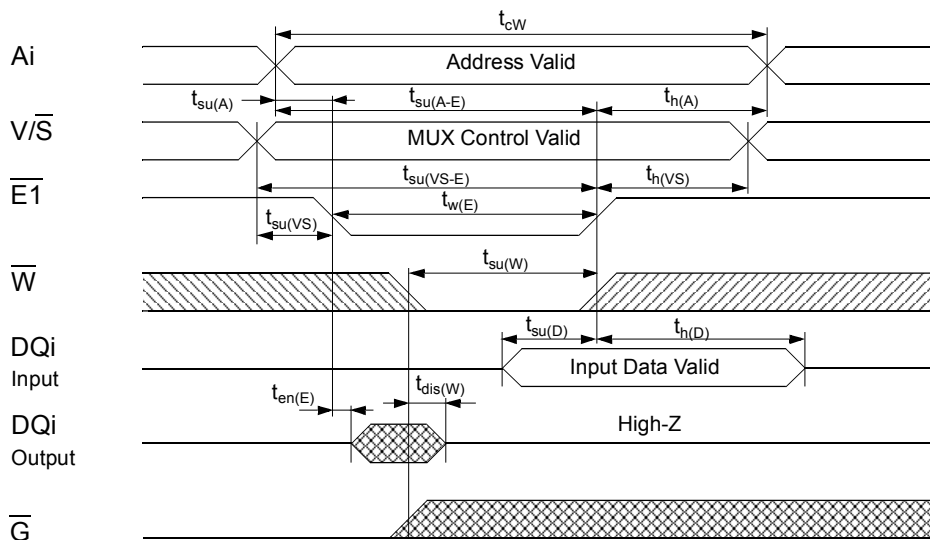
Write Cycle1: \overline{W} -controlled


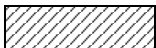
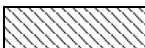
$\overline{E1}$ in the timing diagram represents both $\overline{E1}$ and E2 with $\overline{E1}$ asserted Low and E2 asserted High.



Write Cycle 2: \overline{E} -controlled

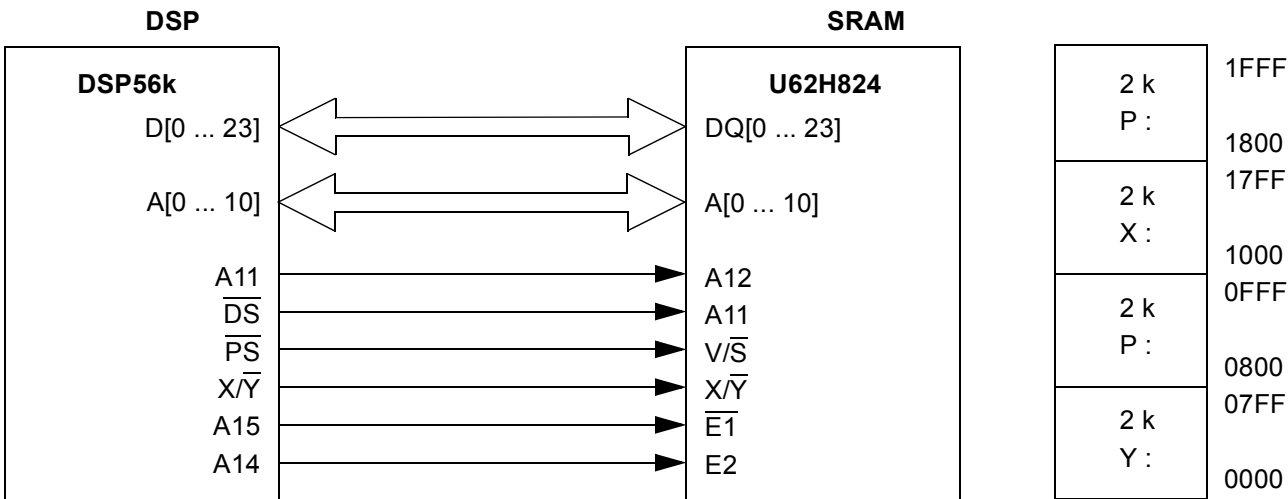
$\overline{E1}$ in the timing diagram represents both $\overline{E1}$ and E2 with $\overline{E1}$ asserted Low and E2 asserted High.



undefined  L- to H-level  H- to L-level 

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Application Example



DSP	SRAM
P : 4000 ... 47FF	0800 ... 0FFF
P : 4800 ... 4FFF	1800 ... 1FFF
X : 4000 ... 4700	1000 ... 17FF
Y : 4000 ... 47FF	0000 ... 07FF

No memory overlap with internal P-, X-, Y-memories.

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